TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC14AP,TC74HC14AF,TC74HC14AFN

Hex Schmitt Inverter

The TC74HC14A is a high speed CMOS SCHMITT INVERTER fabricated with silicon gate C²MOS technology.

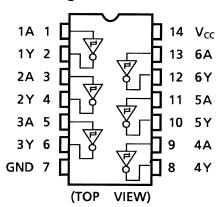
It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the TC74HC04A but the inputs have 25% VCC hysteresis and with its schmitt trigger function, the TC74HC14A can be used as a line receivers which will receive slow input signals.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

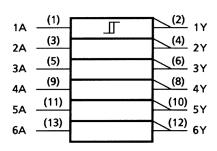
Features

- High speed: $t_{pd} = 11 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 1 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: $V_H = 1.1 \text{ V}$ at $V_{CC} = 5 \text{ V}$
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: | I_{OH}| = I_{OL} = 4 mA (min)
- Balanced propagation delays: t_{pLH} ≃ t_{pHL}
- Wide operating voltage range: V_{CC} (opr) = $2 \sim 6 \text{ V}$
- Pin and function compatible with 74LS14

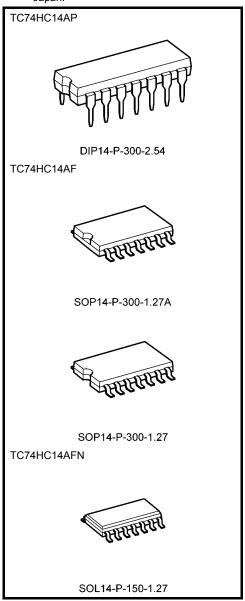
Pin Assignment



IEC Logic Symbol



Note: xxxAFN (JEDEC SOP) is not available in Japan.



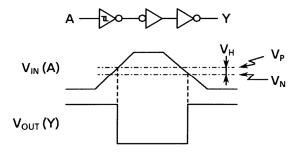
Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOP14-P-300-1.27 : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.)

Truth Table

Α	Υ
L	Н
Н	L

System Diagram, Waveform



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of $Ta = -40^{\circ}C \sim 65^{\circ}C$. From $Ta = 65^{\circ}C$ to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

2



Electrical Characteristics

DC Characteristics

		Test Condition			Ta = 25°C			Ta = -40~85°C		
Characteristics	Symbol				Min	Тур.	Max	Min	Max	Unit
					1.0	1.25	1.50	1.0	1.50	
Positive threshold voltage	V_{P}	_		4.5	2.3	2.70	3.15	2.3	3.15	V
				6.0	3.0	3.50	4.20	3.0	4.20	
				2.0	0.30	0.65	0.9	0.30	0.9	
Negative threshold voltage	V_N		_	4.5	1.13	1.60	2.0	0.13	2.0	V
				6.0	1.50	2.30	2.6	1.50	2.6	
				2.0	0.3	0.6	1.0	0.3	1.0	
Hysteresis voltage	V_{H}	_		4.5	0.6	1.1	1.4	0.6	1.4	V
				6.0	8.0	1.2	1.7	8.0	1.7	
	V _{OH}	V _{IN} = V _{IL}		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9		V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	1
		$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63			
		V _{IN} = V _{IH}		2.0	_	0.0	0.1	_	0.1	
	V_{OL}		$I_{OL} = 20 \ \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _C	V _{IN} = V _{CC} or GND		_	_	1.0	_	10.0	μА

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}\text{C}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH} t _{THL}	_	_	4	8	ns
Propagation delay time	t _{pLH}	_	_	11	21	ns
	t _{pHL}					

3



AC Characteristics (CL = 50 pF, input: $t_r = t_f = 6 \text{ ns}$)

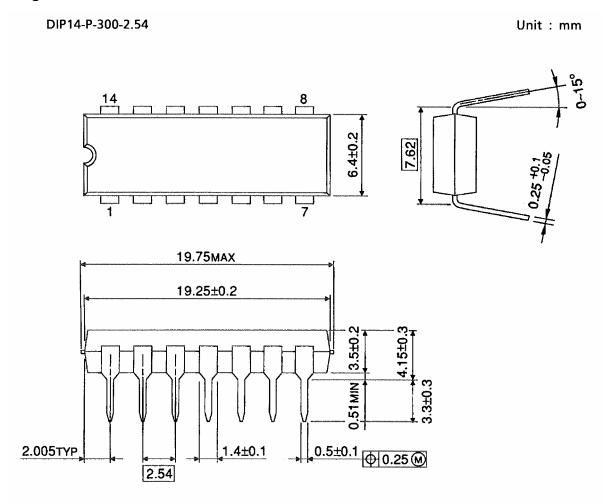
	Test Condition			Ta = 25°C			Ta = -40~85°C		
Characteristics Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
	4		2.0	_	30	75	_	95	
Output transition time	t _{TLH}	_	4.5	_	8	15	_	19	ns
	t _{THL}		6.0	_	7	13	_	16	
			2.0	_	42	125	_	155	
Propagation delay time	t _{pLH}	_	4.5	_	14	25	_	31	ns
	t _{pHL}		6.0	_	12	21	_	26	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation	C _{PD}				28				۲
capacitance	(Note)				20				pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

Package Dimensions

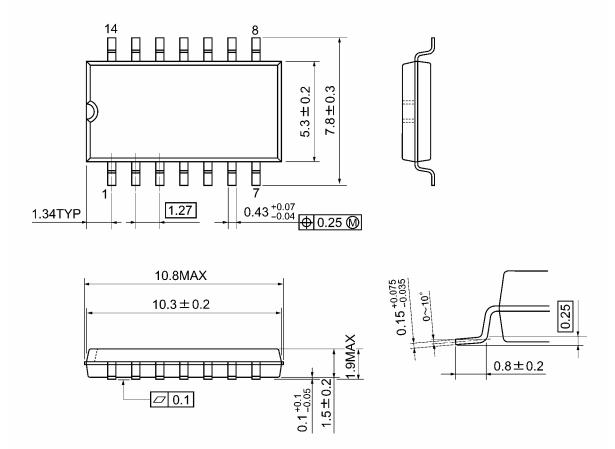


5

Weight: 0.96 g (typ.)

Package Dimensions

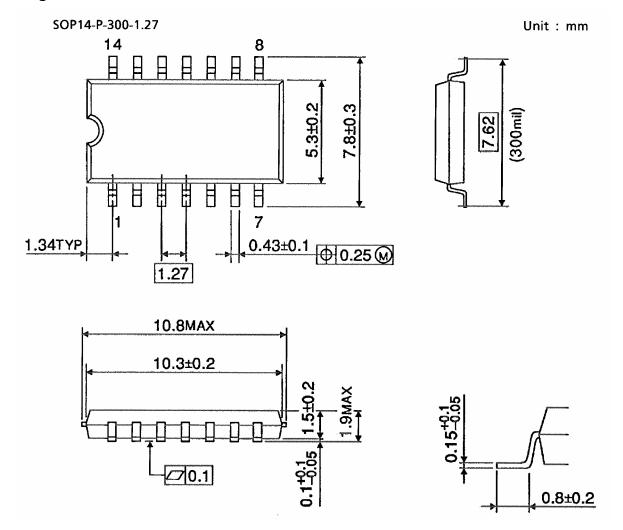
SOP14-P-300-1.27A Unit: mm



6

Weight: 0.18 g (typ.)

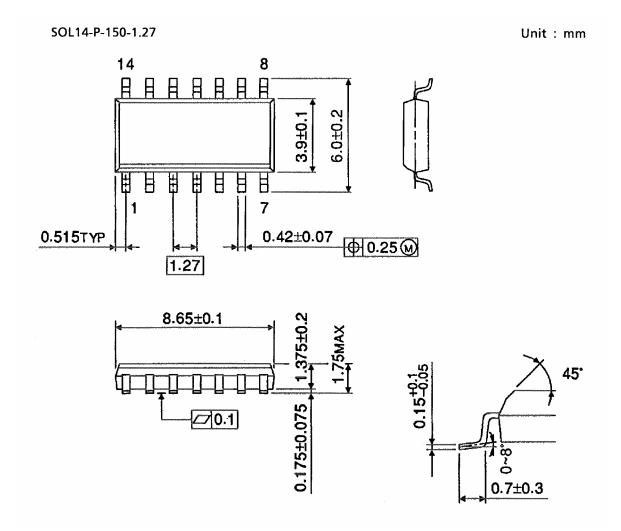
Package Dimensions



Weight: 0.18 g (typ.)



Package Dimensions (Note)



8

Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27

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9